捷多邦,专业PCB打样工厂,2**不上记录26G**, TLC7226E QUADRUPLE 8-BIT DIGITAL-TO-ANALOG CONVERTERS

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features

- Four 8-Bit D/A Converters
- Microprocessor Compatible
- TTL/CMOS Compatible
- Single Supply Operation Possible
- CMOS Technology

applications

- Process Control
- Automatic Test Equipment
- Automatic Calibration of Large System Parameters, e.g. Gain/Offset

DW OR N PACKAGE (TOP VIEW) оитв Г 20 OUTC OUTA [] 2 19 OUTD VSS 3 18 VDD REF [4 17 A0 AGND [16**∏** A1 DGND [1 WR DB7 [14 DB0 13 DB1 DB6 [12 DB2 DB5 **∏** 9 11 DB3 DB4 Π

description

The TLC7226C and TLC7226E consist of four 8-bit voltage-output digital-to-analog converters (DACs) with output buffer amplifiers and interface logic on a single monolithic chip.

Separate on-chip latches are provided for each of the four DACs. Data is transferred into one of these data latches through a common 8-bit TTL/CMOS-compatible 5-V input port. Control inputs A0 and A1 determine which DAC is loaded when WR goes low. The control logic is speed compatible with most 8-bit microprocessors.

Each DAC includes an output buffer amplifier capable of sourcing up to 5 mA of output current.

The TLC7226 performance is specified for input reference voltages from 2 V to V_{DD} – 4 V with dual supplies. The voltage mode configuration of the DACs allows the TLC7226 to be operated from a single power supply rail at a reference of 10 V.

The TLC7226 is fabricated in a LinBiCMOS[™] process that has been specifically developed to allow high-speed digital logic circuits and precision analog circuits to be integrated on the same chip. The TLC7226 has a common 8-bit data bus with individual DAC latches. This provides a versatile control architecture for simple interface to microprocessors. All latch-enable signals are level triggered.

Combining four DACs, four operational amplifiers, and interface logic into either a 0.3-inch wide, 20-terminal dual-in-line IC (DIP) or a small 20-terminal small-outline IC (SOIC) allows a dramatic reduction in board space requirements and offers increased reliability in systems using multiple converters. The pinout is aimed at optimizing board layout with all of the analog inputs and outputs at one end of the package and all of the digital inputs at the other.

The TLC7226C is characterized for operation from 0°C to 70°C. The TLC7226E is characterized for operation from –25°C to 85°C.

AVAILABLE OPTIONS

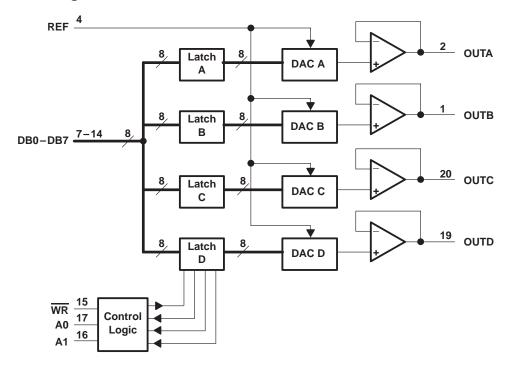
- 5	PACKAGE				
TA	SMALL OUTLINE (DW)	PLASTIC DIP (N)			
0°C to 70°C	TLC7226CDW	TLC7226CN			
-25°C to 85°C	TLC7226EDW	TLC7226EN			

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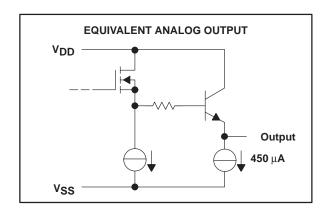




functional block diagram



schematic of outputs





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Terminal Functions

TERMI	TERMINAL				DESCRIPTION		
NAME	NO.†	1/0	DESCRIPTION				
AGND	5		Analog ground. AGND is the reference and return terminal for the analog signals and supply.				
A0, A1	16, 17	ı	DAC select inputs. The combination of high or low levels select either DACA, DACB, DACC, or DACD.				
DGND	6		Digital ground. DGND is the reference and return terminal for the digital signals and supply.				
DB0-DB7	7-14	I	Digital DAC data inputs. DB0-DB7 are the input digital data used for conversion.				
OUTA	2	0	DACA output. OUTA is the analog output of DACA.				
OUTB	1	0	DACB output. OUTB is the analog output of DACB.				
OUTC	20	0	DACC output. OUTC is the analog output of DACC.				
OUTD	19	0	DACD output. OUTD is the analog output of DACD.				
REF	4	ı	Voltage reference input. The voltage level on REF determines the full scale analog output.				
V_{DD}	18		Positive supply voltage input terminal				
VSS	3		Negative supply voltage input terminal				
WR	15	Ī	Write input. WR selects DAC transparency or latch mode. The selected input latch is transparent when WR is low.				

[†] Terminal numbers shown are for the DW and N packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{DD} : AGND or DGND
V _{SS} [‡] –0.3 V to 24 V
Supply voltage range, V _{SS} : AGND or DGND
Voltage range between AGND and DGND17 V to 17 V
Input voltage range, V_I (to DGND)
Reference voltage range: V _{ref} (to AGND) –0.3 V to V _{DD}
V_{ref} (to V_{SS})
Output voltage range, V _O (to AGND) (see Note 1)
Continuous total power dissipation at (or below) T _A = 25°C (see Note 2)500 mW
Operating free-air temperature range, T _A : C suffix
E suffix
Storage temperature range, T _{stq} 65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW or N packages

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. For operation above $T_A = 75^{\circ}C$, derate linearly at the rate of 2 mW/°C.

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V _{DD}		11.4	16.5	V
Supply voltage, VSS		-5.5	0	V
High-level input voltage, VIH		2		V
Low-level input voltage, V _{IL}			0.8	V
Reference voltage, V _{ref}		0	$V_{DD}-4$	V
Load resistance, R _L		2		kΩ
Setup time, address valid before WR↓, t _{su(AW)} (see Figure 6)	V _{DD} = 11.4 V to 16.5 V	0		ns
Setup time, data valid before WR↑, t _{Su(DW)} (see Figure 6)	V _{DD} = 11.4 V to 16.5 V	45		ns
Hold time, address valid before WR↑, th(AW) (see Figure 6)	V _{DD} = 11.4 V to 16.5 V	0		ns
Hold time, data valid before WR↑, th(DW) (see Figure 6)	V _{DD} = 11.4 V to 16.5 V	10		ns
Pulse duration, WR low, t _W (see Figure 6)	V _{DD} = 11.4 V to 16.5 V	50		ns
Operating free-air temperature, T _Δ	C suffix	0	70	°C
Operating nee-all temperature, 1A	E suffix	-25	85	°C



[‡] The VSS terminal is connected to the substrate and must be tied to the most negative supply voltage applied to the device.

NOTES: 1. Output voltages may be shorted to AGND provided that the power dissipation of the package is not exceeded. Typically short circuit current to AGND is 60 mA.

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electrical characteristics over recommended operating free-air temperature range

dual power supply over recommended power supply and reference voltage ranges, AGND = DGND = 0 V (unless otherwise noted)

	PARAM	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Ц	Input current, digital		$V_I = 0 V \text{ or } V_{DD}$			±1	μΑ
I _{DD}			$V_{I} = 0.8 \text{ V or } 2.4 \text{ V}, V_{DD} = 16.5 \text{ V}, \\ V_{SS} = -5 \text{ V}, \qquad \text{No load}$		6	16	mA
ISS	ISS Supply current		V _I = 0.8 V or 2.4 V, No load		4	10	mA
ri(ref)	r _{i(ref)} Reference input resistance			2	4		kΩ
	Power supply sensitivity		$\Delta V_{DD} = \pm 5\%$			0.01	%/%
		REF input	All 0s loaded	65			
Ci	C _i Input capacitance	KET IIIput	All 1s loaded			300	pF
		Digital inputs				8	

operating characteristics over recommended operating free-air temperature range

dual power supply over recommended power supply and reference voltage ranges, AGND = DGND = 0 V (unless otherwise noted)

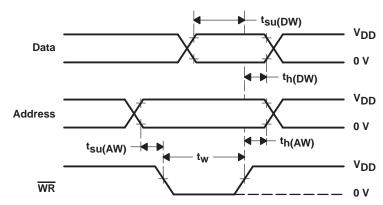
PARAM	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Slew rate			2.5			V•µs
Settling time to 1/2 LSB	Positive full scale	V 4-10 V			5	μs
Setting time to 1/2 LSB	Negative full scale	V _{ref} = 10 V			7	
Resolution				8		bits
Total unadjusted error					±2	LSB
Linearity error	Differential/integral	$V_{DD} = 15 \text{ V} \pm 5\%, V_{ref} = 10$	\		±1	LSB
Full-scale error		$VDD = 15 \text{ V} \pm 5\%, \text{ Vref} = 10$	v		±2	LSB
Gain error				±0.25		LSB
Temperature coefficient of gain	Full scale	$V_{DD} = 14 \text{ V to } 16.5 \text{ V}, V_{ref} = 10$	V	±20		ppm/°C
Temperature coefficient of gain	Zero-code error			±50		μV/°C
Zero-code error				±20	±80	mV
Digital crosstalk glitch impulse area		$V_{ref} = 0$		50		nV∙s

single power supply, $V_{DD} = 14.25 \text{ V}$ to 15.75 V, $V_{SS} = AGND = DGND = 0 \text{ V}$, $V_{ref} = 10 \text{ V}$ (unless otherwise noted)

PARAM	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
Supply current, IDD		V _I = 0.8 V or 2.4 V,	No load		5	13	mA
Slew rate				2			V∙μs
Settling time to 1/2 LSB	Positive full scale					5	
Setting time to 1/2 LSB	Negative full scale					20	μs
Resolution					8		bits
Total unadjusted error						±2	LSB
Full-scale error						±2	LSB
Temperature coefficient of gain	Full scale	$V_{DD} = 14 \text{ V to } 16.5 \text{ V},$	$V_{ref} = 10 V$		±20		ppm/°C
remperature coefficient of gain	Zero-code error				±50		μV/°C
Linearity error	Differential					±1	LSB
Digital crosstalk-glitch impulse area					50		nV∙s



PARAMETER MEASUREMENT INFORMATION



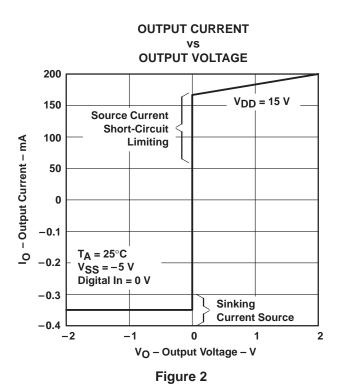
NOTES: A. $t_f = t_f = 20$ ns over V_{DD} range.

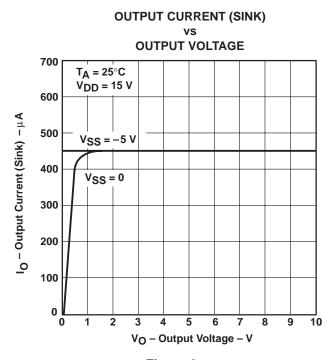
- The timing measurement reference level is equal to V_{IH} + V_{IL} divided by 2.
- C. The selected input latch is transparent while WR is low. Invalid data during this time can cause erroneous outputs.

Figure 1. Write-Cycle Voltage Waveforms



TYPICAL CHARACTERISTICS

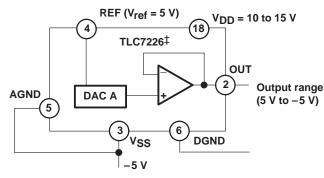




PRINCIPLES OF OPERATION

AGND bias for direct bipolar output operation

The TLC7226 can be used in bipolar operation without adding more external operational amplifiers as shown in Figure 1 by biasing AGND to V_{SS}. This configuration provides an excellent method for providing a direct bipolar output with no additional components. The transfer values are shown in Table 1.



[‡] Digital inputs omitted for clarity.

Figure 4. AGND Bias for Direct Bipolar Operation

DAC LATCH CONTENTS ANALOG OUTPUT MSB LSB + $V_{ref} \left(\frac{127}{128} \right)$ 1111 1111 + $V_{ref} \left(\frac{1}{128}\right)$ 0001 1000 1000 0000 $-V_{ref}\left(\frac{1}{128}\right)$ 0111 1111 0000 0001 0000 0000

Table 1. Bipolar (Offset Binary) Code

AGND bias for positive output offset

The TLC7226 AGND terminal can be biased above or below the system ground terminal, DGND, to provide an offset analog output voltage level. Figure 2 shows a circuit configuration to achieve this for channel A of the TLC7226. The output voltage, V_O , at OUTA can be expressed as:

$$V_{O} = V_{BIAS} + D_{A} (V_{I})$$
 (1)

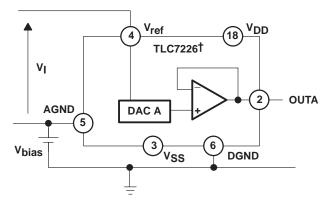
where D_A is a fractional representation of the digital input word (0 \leq D \leq 255/256).

Increasing AGND above system GND reduces the output range. $V_{DD} - V_{ref}$ must be at least 4 V to ensure specified operation. Since the AGND terminal is common to all four DACs, this method biases up the output voltages of all the DACs in the TLC7226. Supply voltages V_{DD} and V_{SS} for the TLC7226 should be referenced to DGND.



PRINCIPLES OF OPERATION

AGND bias for positive output offset (continued)



[†] Digital inputs omitted for clarity.

Figure 5. AGND Bias Circuit

interface logic information

Address lines A0 and A1 select which DAC accepts data from the input port. Table 2 shows the operations of the four DACs. Figure 3 shows the input control logic. When the \overline{WR} signal is low, the input latches of the selected DAC are transparent and the output responds to activity on the data bus. The data is latched into the addressed DAC latch on the rising edge of \overline{WR} . While \overline{WR} is high, the analog outputs remain at the value corresponding to the data held in their respective latches.

Table 2. Function Table

CONTROL INPUTS			OPERATION
WR	A1	A2	OPERATION
Н	Х	Х	No operation
			Device not selected
L	L	L	DAC A transparent
1	L	L	DAC A latched
L	L	Н	DAC B transparent
1	L	Н	DAC B latched
L	Н	L	DAC C transparent
1	Н	L	DAC C latched
L	Н	Н	DAC D transparent
1	Н	Н	DAC D latched

L = low, H = high, X = irrelevant



PRINCIPLES OF OPERATION

interface logic information (continued)

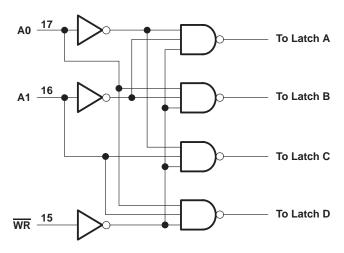


Figure 6. Input Control Logic

unipolar output operation

The unipolar output operation is the basic mode of operation for each channel of the TLC7226, with the output voltages having the same positive polarity as V_{ref} . The TLC7226 can be operated with a single power supply ($V_{SS} = AGND$) or with positive/negative power supplies. The voltage at V_{ref} must never be negative with respect to AGND to prevent parasitic transistor turn-on. Connections for the unipolar output operation are shown in Figure 4. Transfer values are shown in Table 3.



PRINCIPLES OF OPERATION

unipolar output operation (continued)

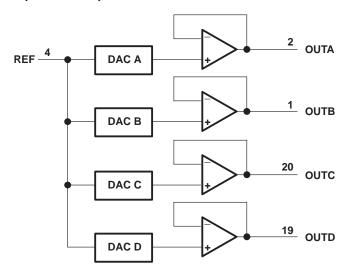


Figure 7. Unipolar Output Circuit

Table 3. Unipolar Code

DAC LATCH CONTENTS		ANALOG OUTPUT		
MSB	LSB			
1111	1111	+ $V_{ref} \left(\frac{255}{256} \right)$		
1000	0001	$+ V_{ref} \left(\frac{129}{256} \right)$		
1000	0000	$+ V_{ref} \left(\frac{128}{256} \right) = + \frac{V_{ref}}{2}$		
0111	1111	$+ V_{ref} \left(\frac{127}{256} \right)$		
0000	0001	$+ V_{ref} \left(\frac{1}{256} \right)$		
0000	0000	0 V		
NOTE A. 1 LSB = $\left(V_{\text{ref}} \ 2^{-8}\right) = V_{\text{ref}} \left(\frac{1}{256}\right)$				

linearity, offset, and gain error using single-ended power supplies

When an amplifier is operated from a single power supply, the voltage offset can still be either positive or negative. With a positive offset, the output voltage changes on the first code change. With a negative offset the output voltage may not change with the first code depending on the magnitude of the offset voltage.

The output amplifier, with a negative voltage offset, attempts to drive the output to a negative voltage. However, because the most negative supply rail is ground, the output cannot be driven to a negative voltage.

So when the output offset voltage is negative, the output voltage remains at zero volts until the input code value produces a sufficient output voltage to overcome the inherent negative offset voltage, resulting in a transfer function shown in Figure 5.



PRINCIPLES OF OPERATION

linearity, offset, and gain error using single-ended power supplies (continued)

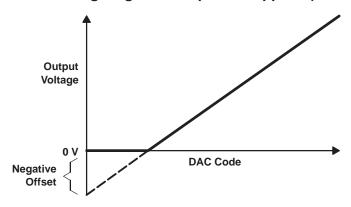


Figure 8. Effect of Negative Offset (Single Power Supply)

This negative offset error, not the linearity error, produces the breakpoint. The transfer function would have followed the dotted line if the output buffer could be driven to a negative voltage.

For a DAC, linearity is measured between zero input code (all inputs 0) and full scale code (all inputs 1) after offset and full scale are adjusted out or accounted for in some way. However, single power supply operation does not allow for adjustment when the offset is negative due to the breakpoint in the transfer function. So the linearity in the unipolar mode is measured between full scale code and the lowest code which produces a positive output voltage.

The code is calculated from the maximum specification for the negative offset.



APPLICATION INFORMATION

bipolar output operation using external amplifier

Each of the DACs of the TLC7226 can also be individually configured to provide bipolar output operation, using an external amplifier and two resistors per channel. Figure 9 shows a circuit used to implement offset binary coding (bipolar operation) with DAC A of the TLC7226. In this case:

$$V_{O} = 1 + \frac{R2}{R1} \times \left(D_{A} \times V_{ref}\right) - \frac{R2}{R1} \times \left(V_{ref}\right)$$
 (2)

with R1 = R2

$$V_{O} = (2D_{A} - 1) \times V_{ref}$$

where $\mathbf{D}_{\mathbf{A}}$ is a fractional representation of the digital word in latch $\mathbf{A}.$

Mismatch between R1 and R2 causes gain and offset errors. Therefore, these resistors must match and track over temperature. The TLC7226 can be operated with a single power supply or from positive and negative power supplies.

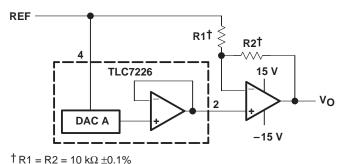


Figure 9. Bipolar Output Circuit

staircase window comparator

In many test systems, it is important to be able to determine whether some parameter lies within defined limits. The staircase window comparator shown in Figure 10 is a circuit that can be used to measure the V_{OH} and V_{OL} thresholds of a TTL device under test. Upper and lower limits on both V_{OH} and V_{OL} can be programmed using the TLC7226. Each adjacent pair of comparators forms a window of programmable size (see Figure 11). When the test voltage (V_{test}) is within a window, then the output for that window is higher. With a reference of 2.56 V applied to the REF input, the minimum window size is 10 mV.



APPLICATION INFORMATION

staircase window comparator (continued)

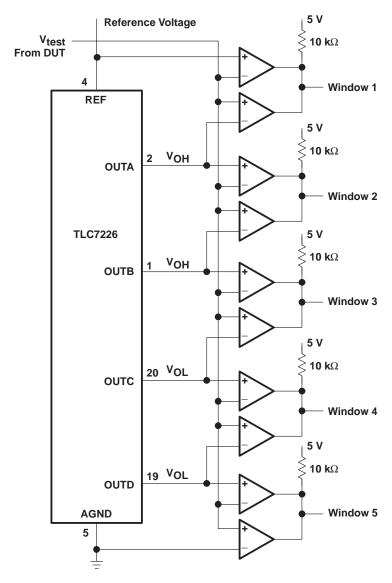


Figure 10. Logic Level Measurement

APPLICATION INFORMATION

staircase window comparator (continued)

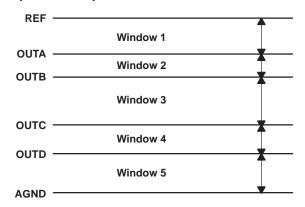


Figure 11. Adjacent Window Structure

The circuit can easily be adapted as shown in Figure 12 to allow for overlapping of windows. When the three outputs from this circuit are decoded, five different nonoverlapping programmable window possibilities can again be defined (see Figure 13).

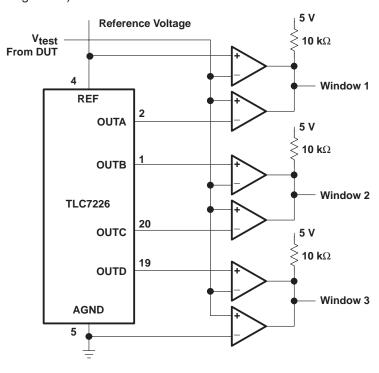


Figure 12. Overlapping Window Circuit

APPLICATION INFORMATION

staircase window comparator (continued)

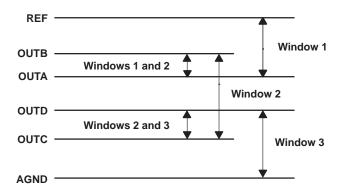


Figure 13. Overlapping Window Structure

output buffer amplifier

The unity-gain output amplifier is capable of sourcing 5 mA into a 2-k Ω load and can drive a 3300-pF capacitor. The output can be shorted to AGND indefinitely or it can be shorted to any voltage between V_{SS} and V_{DD} consistent with the maximum device power dissipation.

multiplying DAC

The TLC7226 can be used as a multiplying DAC when the reference signal is maintained between 2 V and $V_{DD} - 4$ V. When this configuration is used, V_{DD} should be 14.25 V to 15.75 V. A low output-impedance buffer should be used so that the input signal is not loaded by the resistor ladder. Figure 14 shows the general schematic.

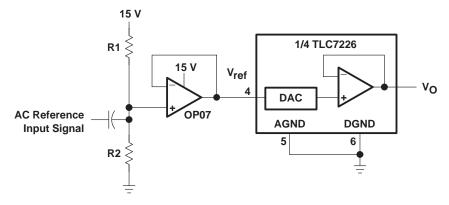


Figure 14. AC Signal Input Scheme



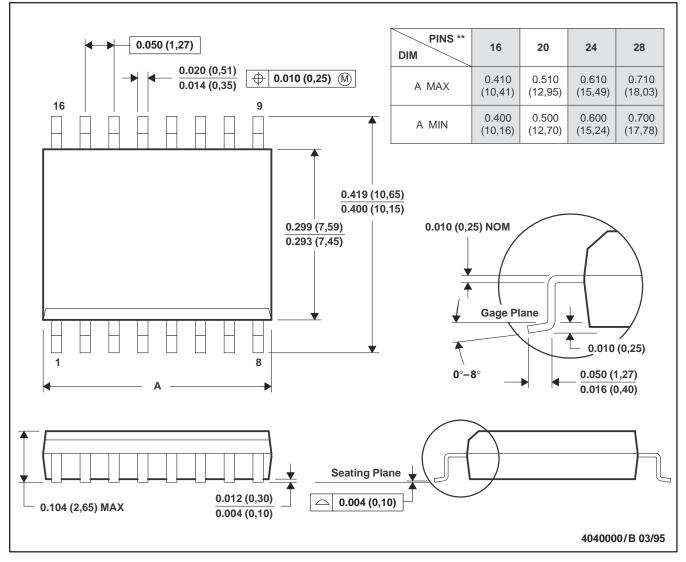
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MECHANICAL DATA

DW (R-PDSO-G**)

16 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013



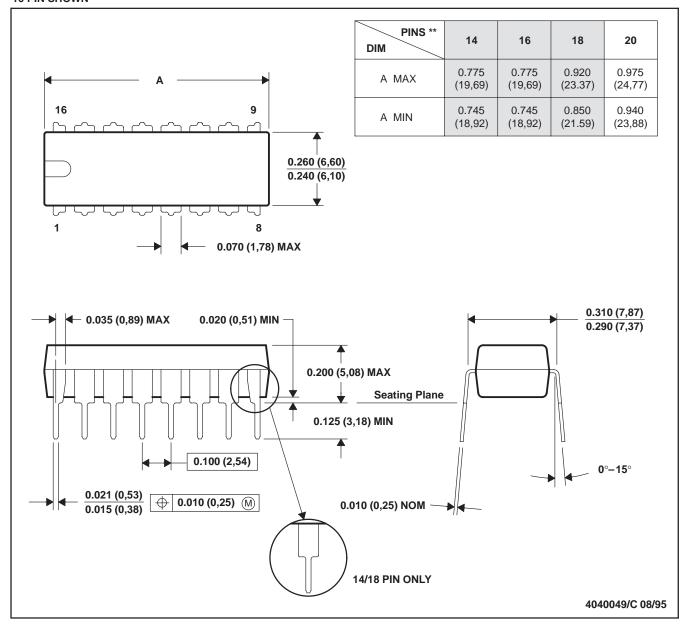
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MECHANICAL DATA

N (R-PDIP-T**)

16 PIN SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 (20 pin package is shorter then MS-001)



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